

New development in the physics of  
Van der Waals forces.  
Moscow, June 20, 2008

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# Van der Waals forces-theory.

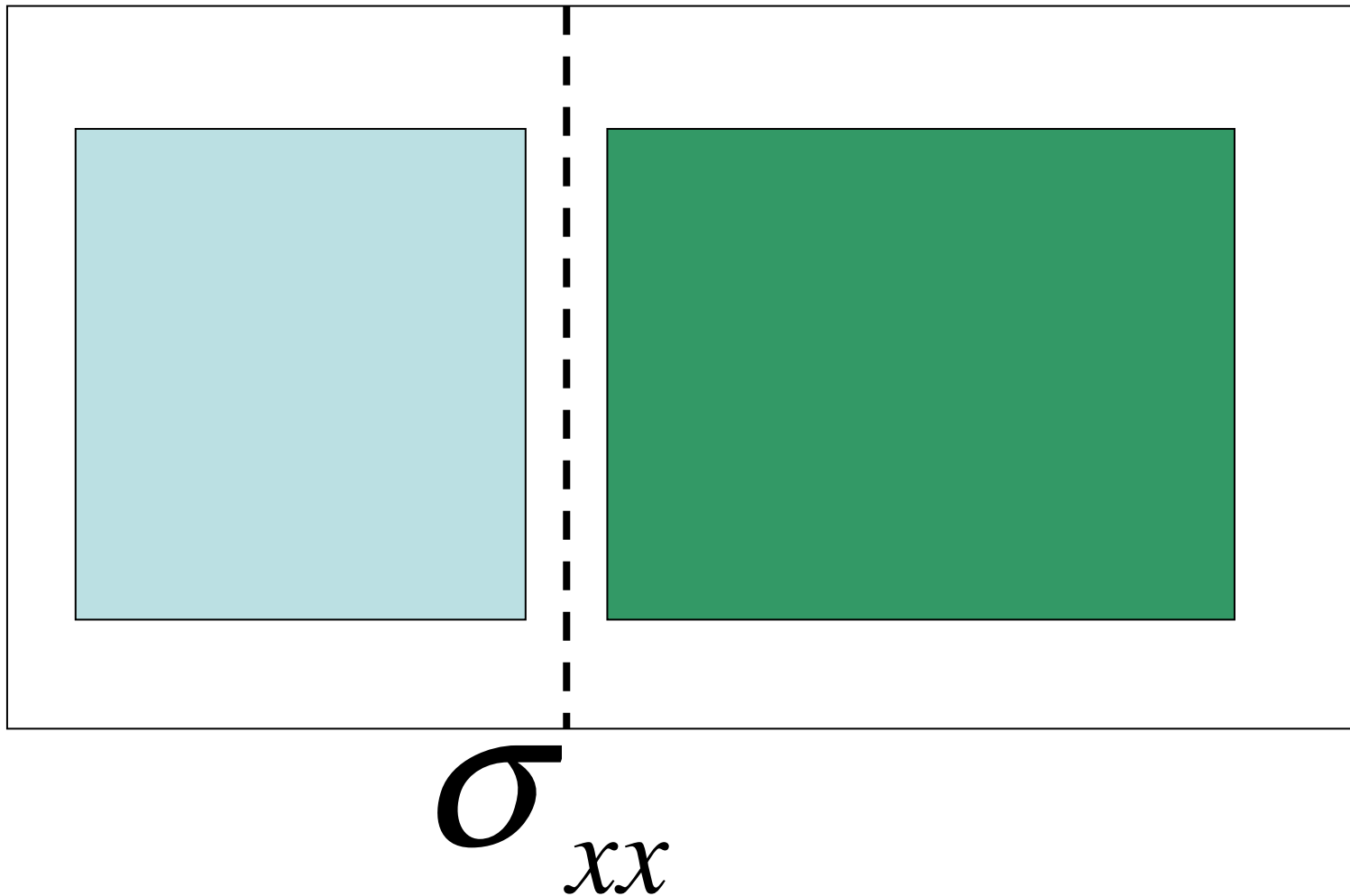
- Van der Waals, about 1890
- F. London (1928). QM derivation of  $1/r^6$  law.
- H.D.B. Casimir, D. Polder (1948). Effects of returning, Macroscopic approach to interaction of ideal metals.
- E.M. Lifshitz (1954). General theory of interaction of dielectric bodies. Thermal effects.
- I.E. Dzyaloshinskii, E.M. Lifshitz, L.P. Pitaevskii (1959). Interaction through dielectric medium. Green's function representation.
- C.Henkel et al. (2002); M. Antezza, L.P. Pitaevskii, S.Stringari (2004). Non-equilibrium effects.

# Correlations of random polarizations

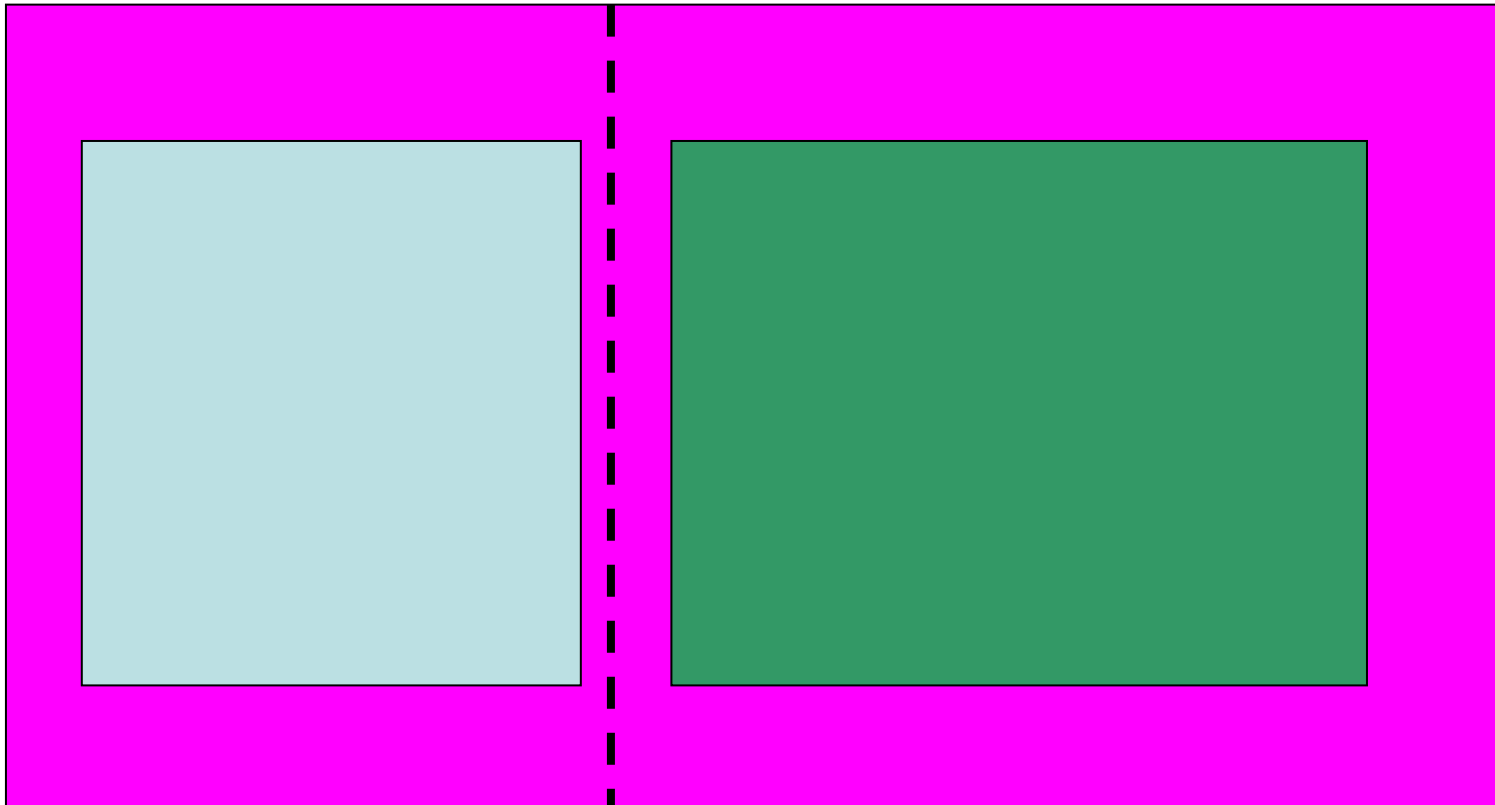
$$\langle P_i(\mathbf{r})P_k(\mathbf{r}_1) \rangle_\omega = \varepsilon'(\omega, \mathbf{r}) \hbar \coth\left(\frac{\hbar\omega}{2T}\right) \delta(\mathbf{r} - \mathbf{r}_1) \delta_{ik}$$

S.M.Rytov (1954); L.D.Landau, E.M.Lifshitz (1958).

# Interaction through vacuum

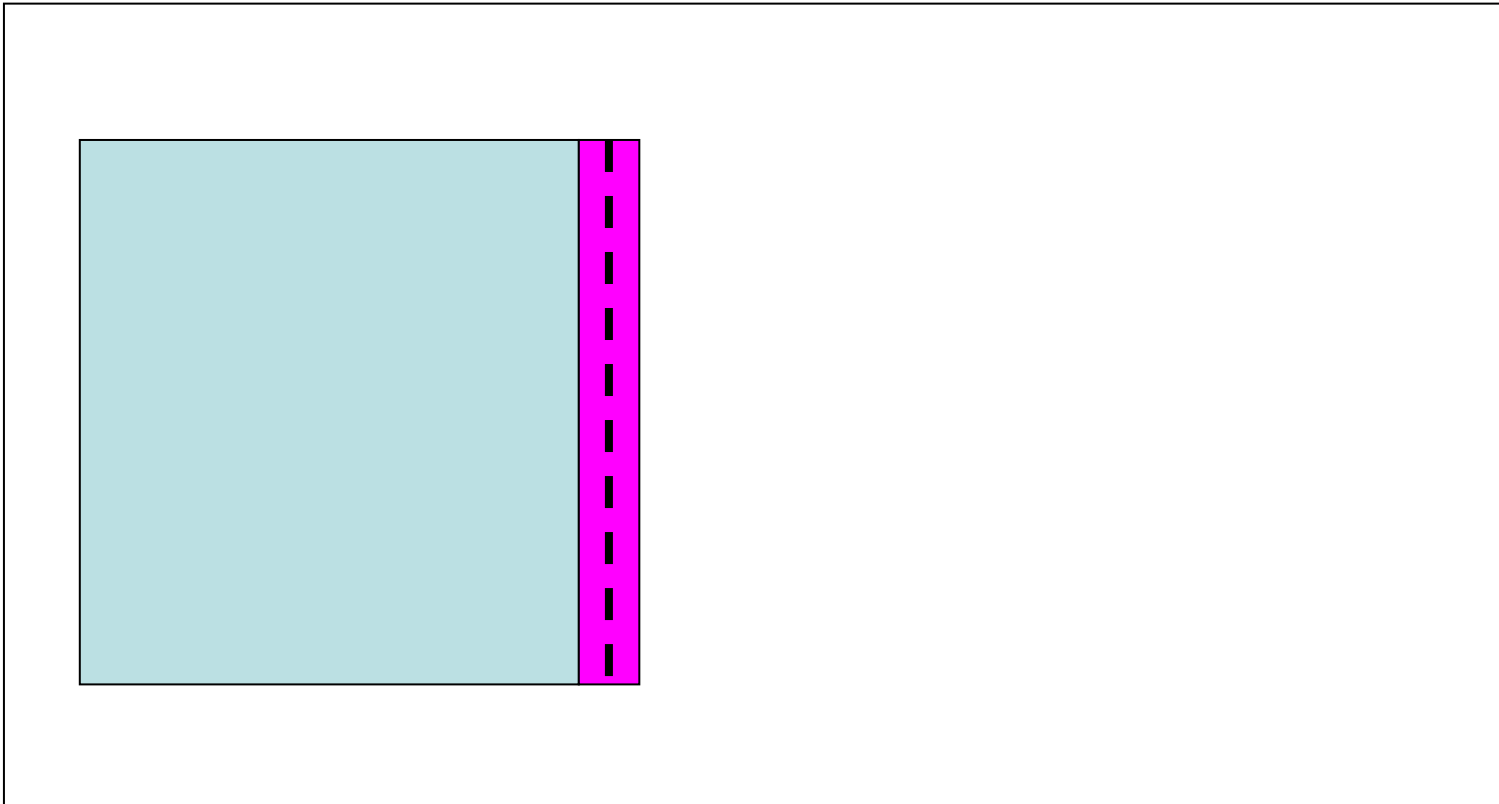


# Interaction through medium



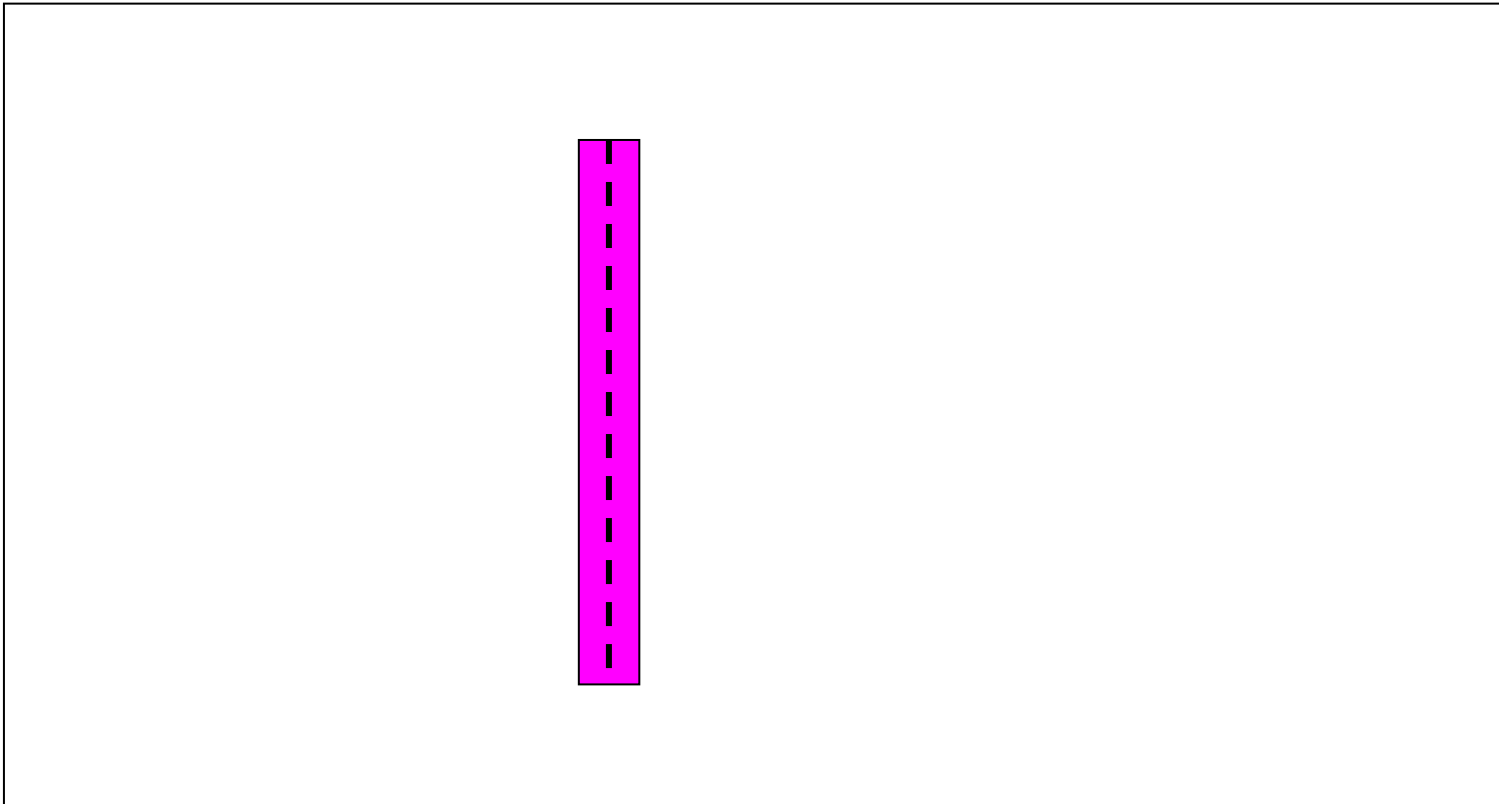
$$\sigma_{xx} = ?$$

# Problem of a film



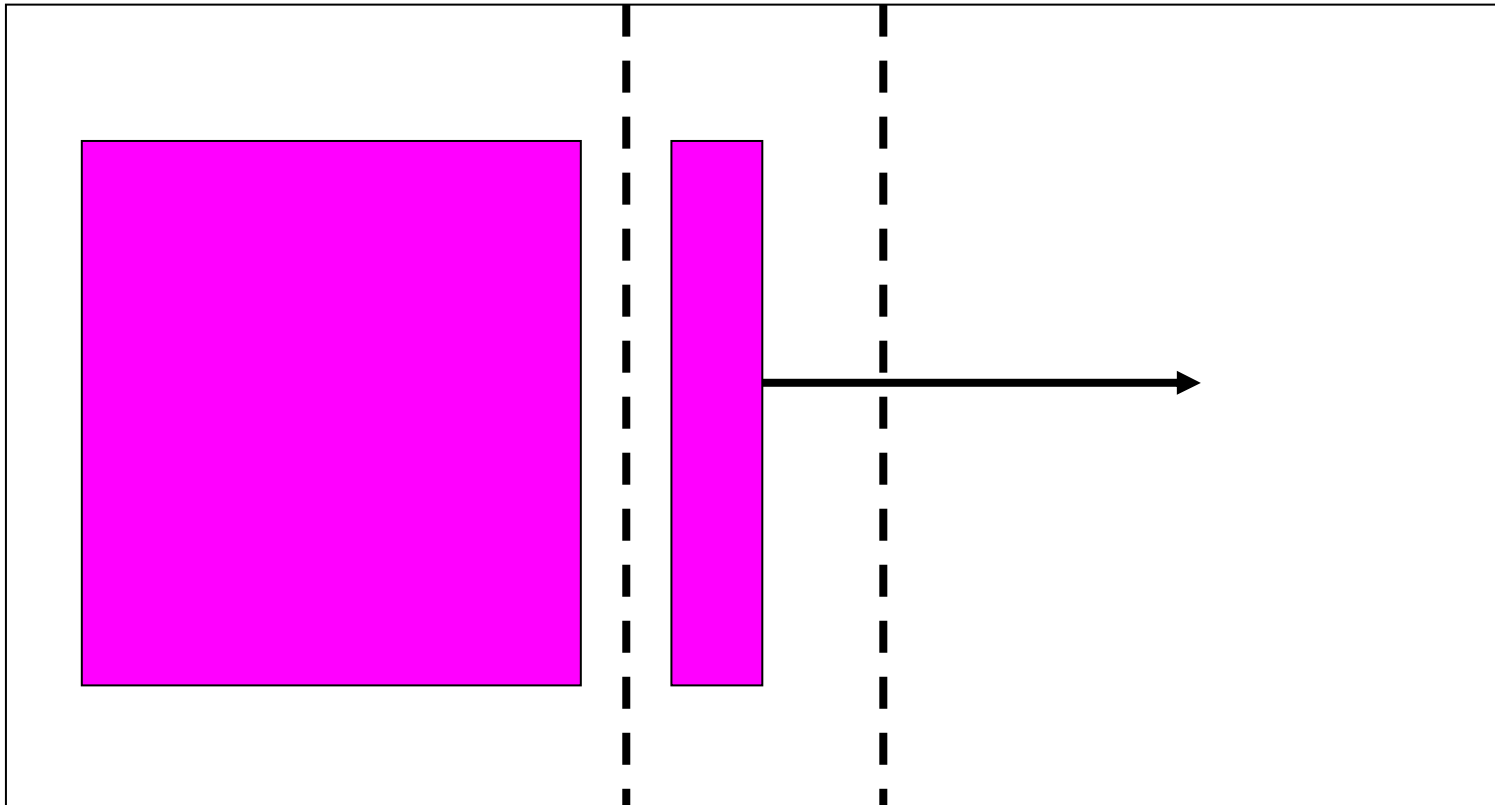
$$\mu(d) = \sigma_{xx}(d)$$

# Problem of a film in vacuum



$$\mu(d) = \mu_{\infty} + \delta\mu(d)$$

# Solution of the problem of a film





# Free energy variation

Free energy variation :

$$\delta F = \frac{T}{4\pi\hbar} \sum_{s=0}^{\infty} \int \mathbf{D}_{ll}^E(\zeta_s, \mathbf{r}, \mathbf{r}) \delta \varepsilon(i|\zeta_s|, \mathbf{r}) d^3x$$

(I. Dzyaloshinskii, L. Pitaevskii, 1959)

# Energy of atom-surface interaction

Free energy variation :

$$\delta F = \frac{T}{4\pi\hbar} \sum_{s=0}^{\infty} \int D_{ll}^E(\zeta_s, \mathbf{r}, \mathbf{r}) \delta\epsilon(i|\zeta_s|, \mathbf{r}) d^3x$$

$$\delta\epsilon(i|\zeta_s|, \mathbf{r}) = 4\pi\alpha(i|\zeta_s|) \delta(\mathbf{r} - \mathbf{r}')$$

Atom - surface potential :

$$V(l) = \frac{T}{\hbar} \sum_{s=0}^{\infty} \alpha(i|\zeta_s|) \left[ D_{ll}^E(\zeta_s, \mathbf{r}, \mathbf{r}) \right]_{\mathbf{r} \rightarrow \mathbf{r} \rightarrow \mathbf{r}_a}$$

# Asymptotic in equilibrium Lifshitz theory

1. Londonregime:  $z \ll \lambda_0$ :  $F = -A/z^4$

$$A = \frac{\hbar}{4\pi} \int_0^{\infty} \alpha(i\xi) \frac{\varepsilon(i\xi) - 1}{\varepsilon(i\xi) + 1} d\xi$$

2. Casimir-Polderregime:

$\lambda_0 \ll z \ll \lambda_T = \hbar c / k_B T$ :  $F = -B/z^5$

$$B = \frac{3\hbar c}{2\pi} \alpha_0 \frac{\varepsilon_0 - 1}{\varepsilon_0 + 1} \varphi(\varepsilon_0); \quad \varepsilon_0 \equiv \varepsilon(\omega = 0)$$

3. Lifshitzregime:

$$\lambda_T \ll z: \quad F = -C/z^4 \quad C = \frac{3k_B T}{4} \alpha_0 \frac{\varepsilon_0 - 1}{\varepsilon_0 + 1}$$

## Relevant length scales

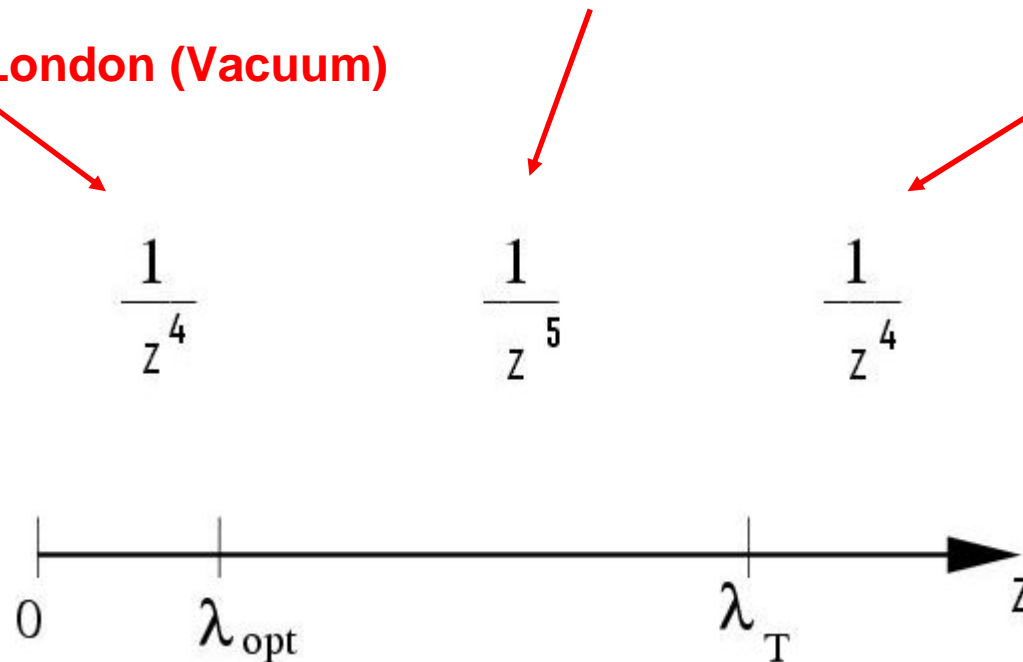
-**Optical** length  $\lambda_{opt}$  fixed by optical properties of the substrate (typically fractions of microns)

- **Thermal photon** wavelength ( $\lambda_T = \hbar c / k_B T \approx 7.6 \mu m$  at room temperature)

### Casimir-Polder (Vacuum+retardation)

van der Waals-London (Vacuum)

Lifshitz (Thermal)



# Dynamic dielectric and polarizability functions

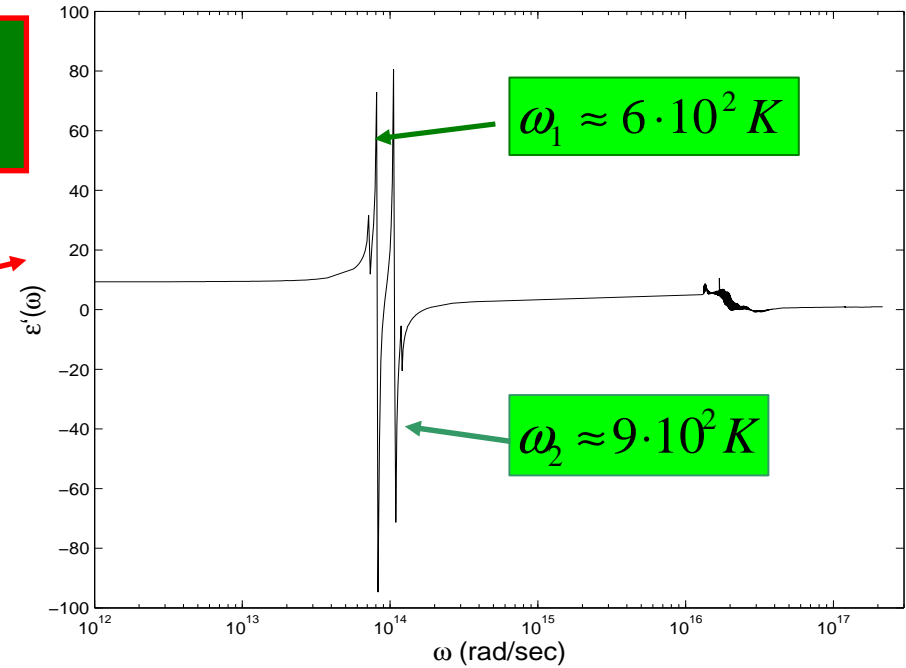
Sapphire substrate

$$\varepsilon(\omega) = \varepsilon'(\omega) + i\varepsilon''(\omega)$$

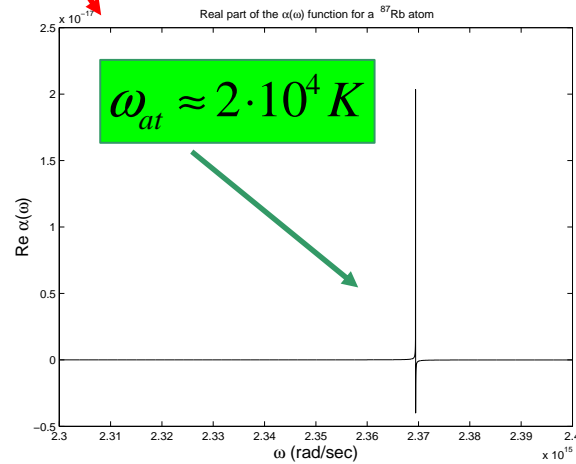
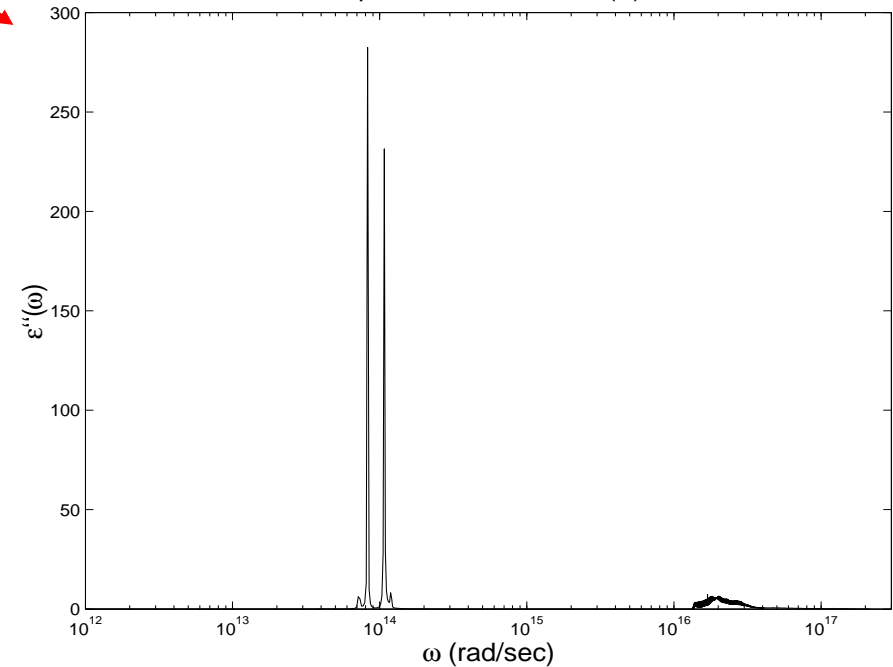
Rubidium atoms

$$\alpha(\omega) = \alpha'(\omega) + i\alpha''(\omega)$$

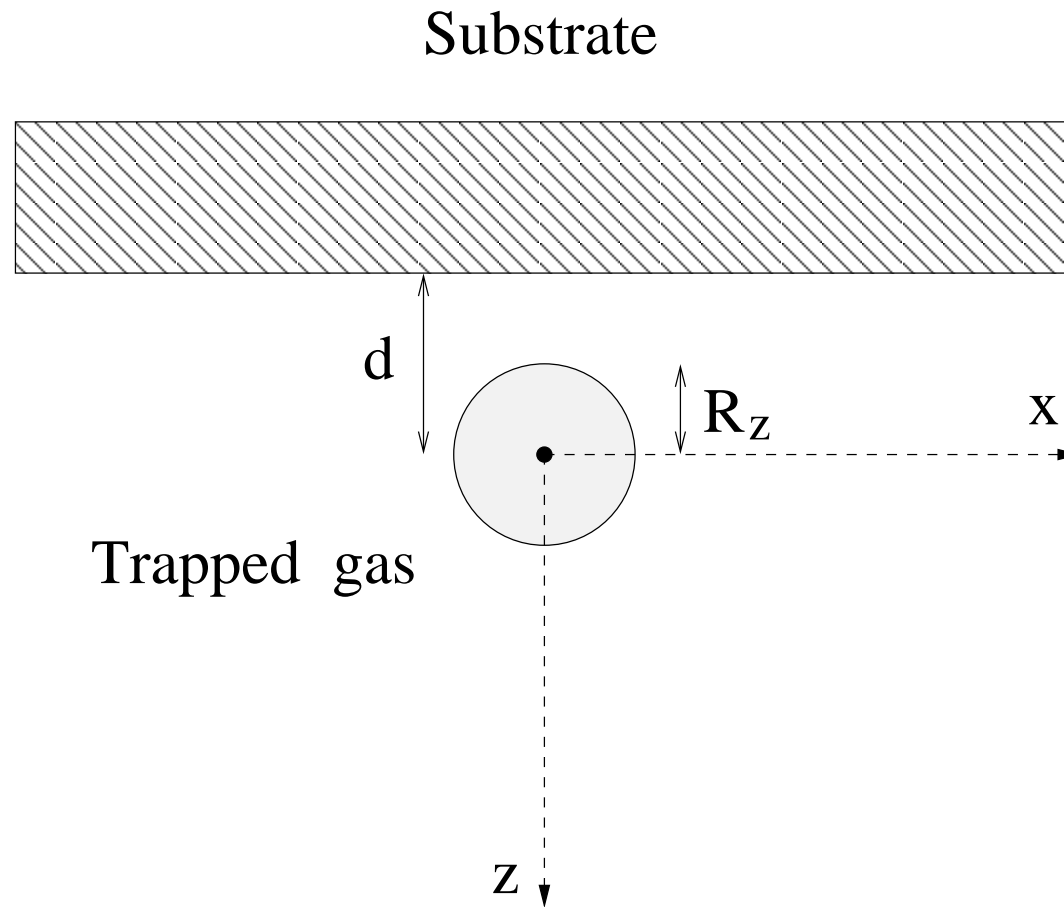
Experimental data of  $\varepsilon'(\omega)$



Experimental data of  $\varepsilon''(\omega)$

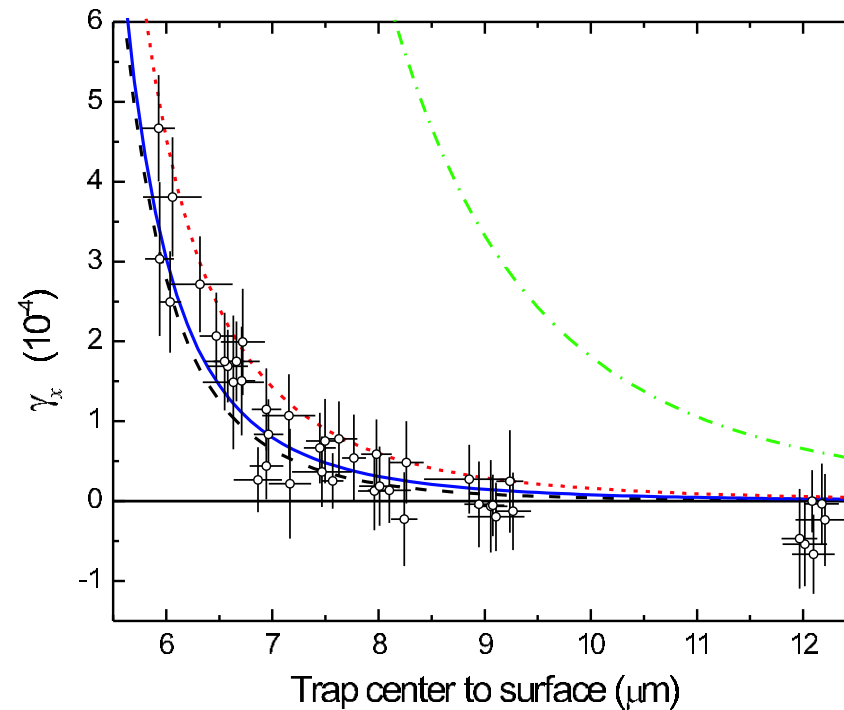


# JILA experimental setup



# JILA RESULTS

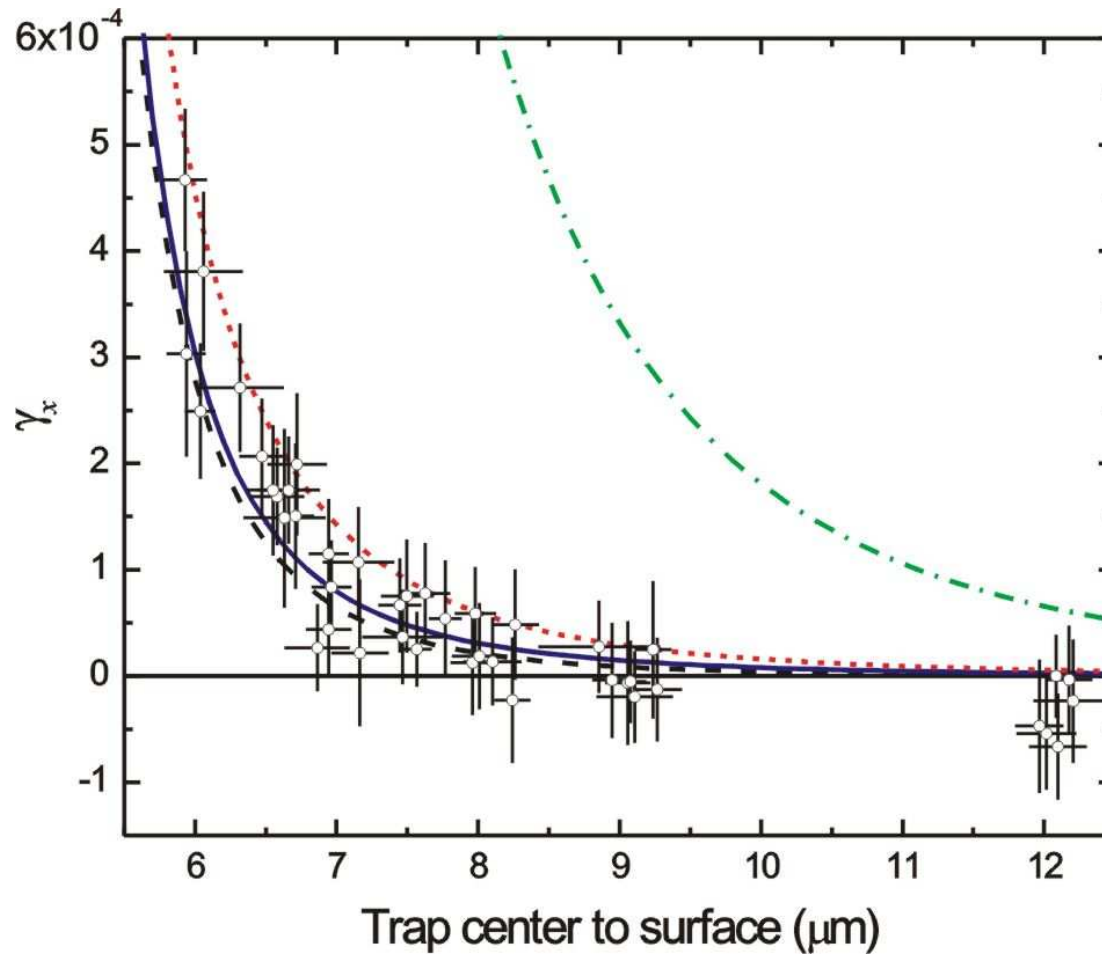
$$\gamma \equiv -\frac{\Delta\omega}{\omega} = -\frac{1}{2\omega m} \langle \partial_z F \rangle$$



Theory: T=0-dash black; T=300K-solid blue; T=600K dot red;  
extrapolation of  $1/d^3$  law-dash dot green

# Equilibrium JILA results

$$\gamma \equiv -\frac{\Delta\omega}{\omega} = -\frac{1}{2\omega m} \langle \partial_z F \rangle$$

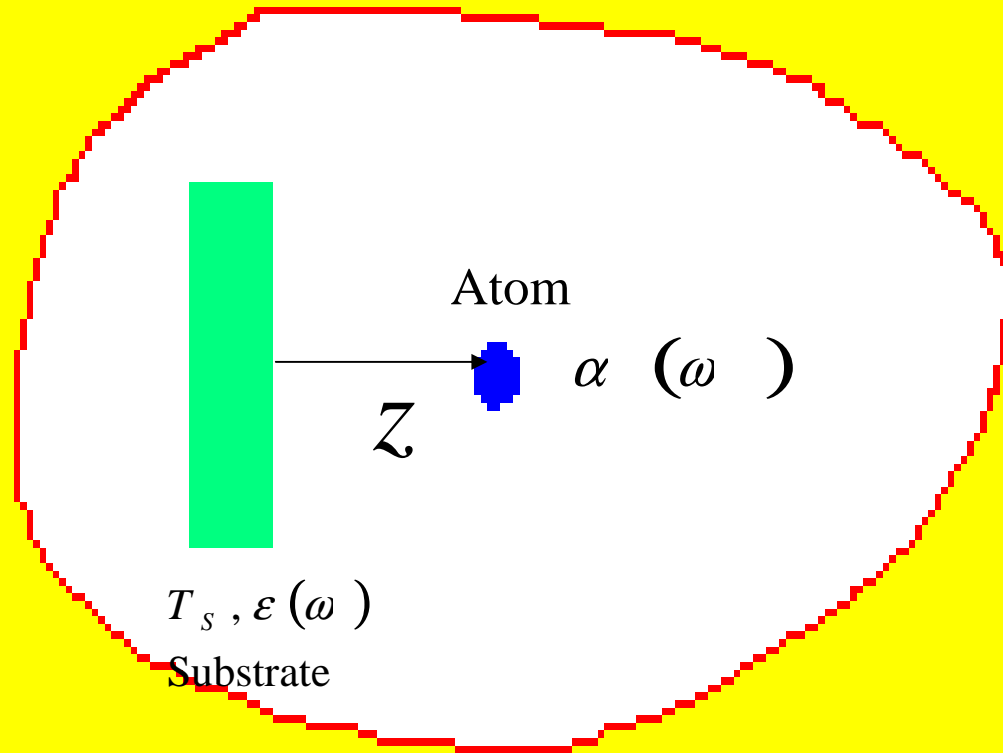




# Non-equilibrium setting

Environment

$T_E$



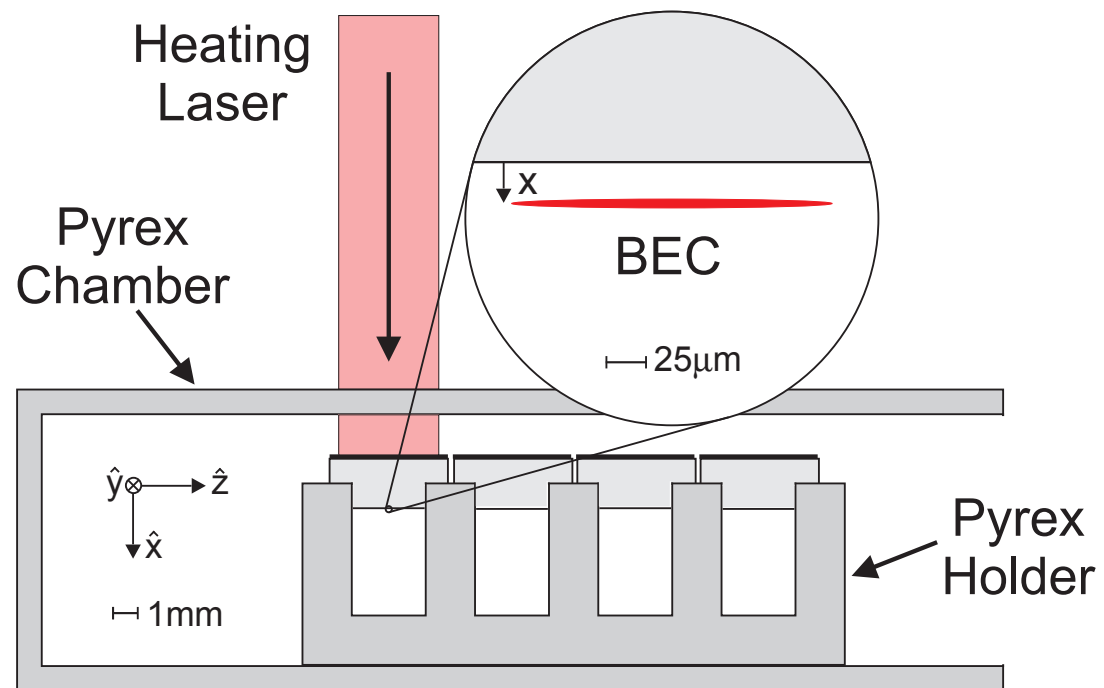
Atom

$z$

$\alpha (\omega)$

$T_s, \epsilon(\omega)$

Substrate



# Non-equilibrium force

The main assumption :

$$k_B T_S, k_B T_S \ll \hbar \omega_{at}; \alpha(\omega) \rightarrow \alpha_0$$

$$F = 4\pi\alpha_0 \frac{\partial \langle E^2 \rangle}{\partial z \cdot 8\pi}$$

# Non-equilibrium fluctuations

$$\langle P_i(\mathbf{r})P_k(\mathbf{r}_1) \rangle_\omega = \varepsilon'(\omega, \mathbf{r})\hbar \coth\left(\frac{\hbar\omega}{2T}\right)\delta(\mathbf{r} - \mathbf{r}_1)\delta_{ik}$$

$$T \rightarrow T(\mathbf{r}) \quad ???$$

$$F_{th}^{neq}(T, \mathbf{0}, z) =$$

$$\frac{\hbar\alpha}{2\pi^2} \int_0^\infty d\omega \frac{\varepsilon'(\omega)}{e^{\hbar\omega/T} - 1} \operatorname{Re} \left[ \int G_{ik}(\omega; \mathbf{r}, \mathbf{r}_1) \partial_z G_{ik}^*(\omega; \mathbf{r}, \mathbf{r}_1) \right] d^3\mathbf{r}_1$$

Simplifying assumption:  
substrate is transparent

$$k_B T_S, k_B T_S \ll \hbar \omega_{opt}$$

$$\epsilon(\omega) \rightarrow \epsilon(0) \equiv \epsilon_0$$

# Asymptotic of the non-equilibrium thermal force

**The force is created by the evanescent waves. Only the radiation, which undergoes the total reflection, is important.**

**Asymptotically the evanescent waves near the total reflection angle ( $\sin^2\theta_r=1/\varepsilon$ ) are important. They decay slowly on the vacuum side.**



# Energy density of evanescent waves

$$\frac{\langle \mathbf{E}^2 \rangle}{8\pi} \sim \int_{k_{\perp}=\omega/c}^{k_{\perp}=\sqrt{\epsilon}\omega/c} |\mathbf{E}_{\mathbf{k}}(z=0)|^2 e^{-2z\kappa} \frac{2d^3\mathbf{k}_0}{(2\pi)^3}$$

$$\kappa = \sqrt{k_{\perp}^2 - \omega^2 / c^2} \sim 1/z$$

$\mathbf{E}_{\mathbf{k}}(z=0)$  can be expressed in terms of field in the substrate using Fresnel equations



# Energy density of evanescent waves

$$\frac{\langle \mathbf{E}^2 \rangle}{8\pi} = \frac{1 + \varepsilon}{\varepsilon} \int_{k_{\perp} = \omega/c}^{k_{\perp} = \sqrt{\varepsilon}\omega/c} \frac{\hbar\omega}{e^{\hbar\omega/T_S} - 1} e^{-2z\kappa} \frac{2d^3\mathbf{k}_0}{(2\pi)^3}$$

$$\kappa = \sqrt{k_{\perp}^2 - \omega^2 / c^2} \sim 1/z$$

# Asymptotic of the energy

$$z \rightarrow \infty : k_{\perp} \rightarrow \omega / c, \kappa = \sqrt{k_{\perp}^2 - \omega^2 / c^2} \rightarrow 0$$

$$d^3 \mathbf{k}_0 = 2\pi k_{\perp} dk_{\perp} dk_{0z} \approx \frac{2\pi\epsilon}{c\sqrt{\epsilon-1}} \kappa d\kappa d\omega$$

$$\begin{aligned} U_E &= \frac{\langle \mathbf{E}^2 \rangle}{8\pi} = \frac{1+\epsilon}{2\pi^2 c\sqrt{\epsilon-1}} \int_0^{\infty} \frac{\hbar\omega d\omega}{e^{\hbar\omega/T_S} - 1} \int_0^{\infty} e^{-2z\kappa} \kappa d\kappa \\ &= \frac{1}{48} \frac{1+\epsilon}{z^2 \sqrt{\epsilon-1}} \frac{k_B^2 T_S^2}{c\hbar} \end{aligned}$$

# Characteristic interval of angles

$$\frac{\omega^2}{c^2} \sin \theta_r d\theta \sim \kappa d\kappa$$

$$z \rightarrow \infty : \kappa \sim 1/z, \omega \sim k_B T / \hbar,$$

$$\Delta\theta \sim \frac{c^2}{(k_B T)^2 z^2} \sim \frac{\lambda_T^2}{z^2}$$

$$U_E \sim \frac{\lambda_T^2}{z^2} U_{BB} \sim \frac{1}{z^2} \frac{k_B^2 T^2}{c\hbar}$$

# Physical meaning

Only incident waves in the small interval of solid angles of the order of  $(c/Tz)^2$  near the total reflection angle are important. Hence  $U_E \sim (c/Tz)^2 U_{BB}$  where  $U_{BB}$  is the energy of the black-body radiation.

# Asymptotic of the non-equilibrium thermal force

$$F_{th}^{neq} = 4\pi\alpha_0 \frac{\partial}{\partial z} \left\langle \frac{E^2}{8\pi} \right\rangle =$$
$$= -\alpha_0 \frac{\pi}{6} \frac{1 + \varepsilon}{z^3 \sqrt{\varepsilon - 1}} \frac{k_B^2 T_S^2}{c\hbar}$$

Antezza , Pitaevskii , Stringari ,

PRL **95**, 113202 (2005)

# Finite temperatures of substrate and environment

$$F^{neq}(T, 0, z) \propto 1/z^3; F^{eq}(T, z) \propto 1/z^4;$$

$$z \rightarrow \infty: F^{neq}(T, 0, z) + F^{neq}(0, T, z) = 0$$

$$z \gg \lambda_T / \sqrt{\epsilon_0 - 1}:$$

$$F^{neq}(T_S, T_E, z) = -\frac{\pi k_B^2 (T_S^2 - T_E^2)}{z^3 6c\hbar} \alpha_0 \frac{\epsilon + 1}{\sqrt{\epsilon - 1}}$$

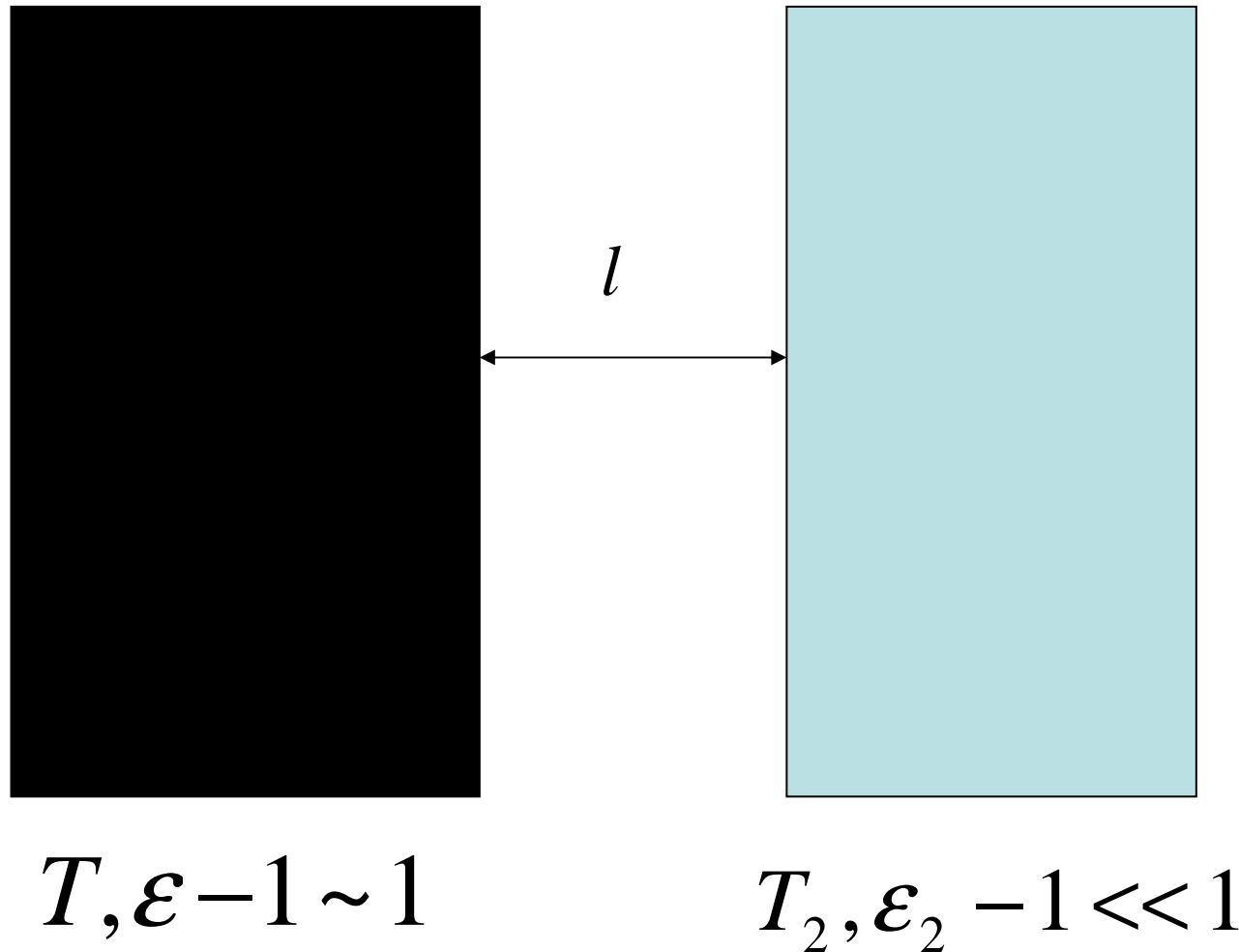
# Metallic substrate

For a metallic substrate

$$\varepsilon(\omega) = i \frac{4\pi\sigma}{\omega}$$

$$F^{neq}(T_S, T_E, z) = - \frac{2.6 k_B^{3/2} (T_S^{3/2} - T_E^{3/2})}{z^3 c \sqrt{2\hbar}} \alpha_0 \sqrt{\sigma}$$

# Atomic cloud as a limit of a rarefied body





# Atom-surface interaction as a limit of the interaction of a rarefied body

**Equilibrium Lifshitz theory:**

$$T = T_2, \text{ at } \lambda_T \ll l, \varepsilon_2 - 1 \ll 1:$$

$$P^{eq} \propto \frac{k_B T}{l^3} (\varepsilon_2 - 1) = \frac{k_B T}{l^3} 4\pi\alpha N$$

$$U_E = -P / N$$

# Non-additivity at large distances out of equilibrium

$$T \neq T_2 = 0, \epsilon_2 - 1 \ll 1:$$

1. At  $\lambda_T \ll l \ll \lambda_T / \sqrt{\epsilon_2 - 1}$ :

$$P^{neq} \propto \frac{(k_B T)^2}{l^2 c \hbar} (\epsilon_2 - 1) = \frac{(k_B T)^2}{l^2 c \hbar} 4\pi\alpha N$$

# Non-additivity at large distances

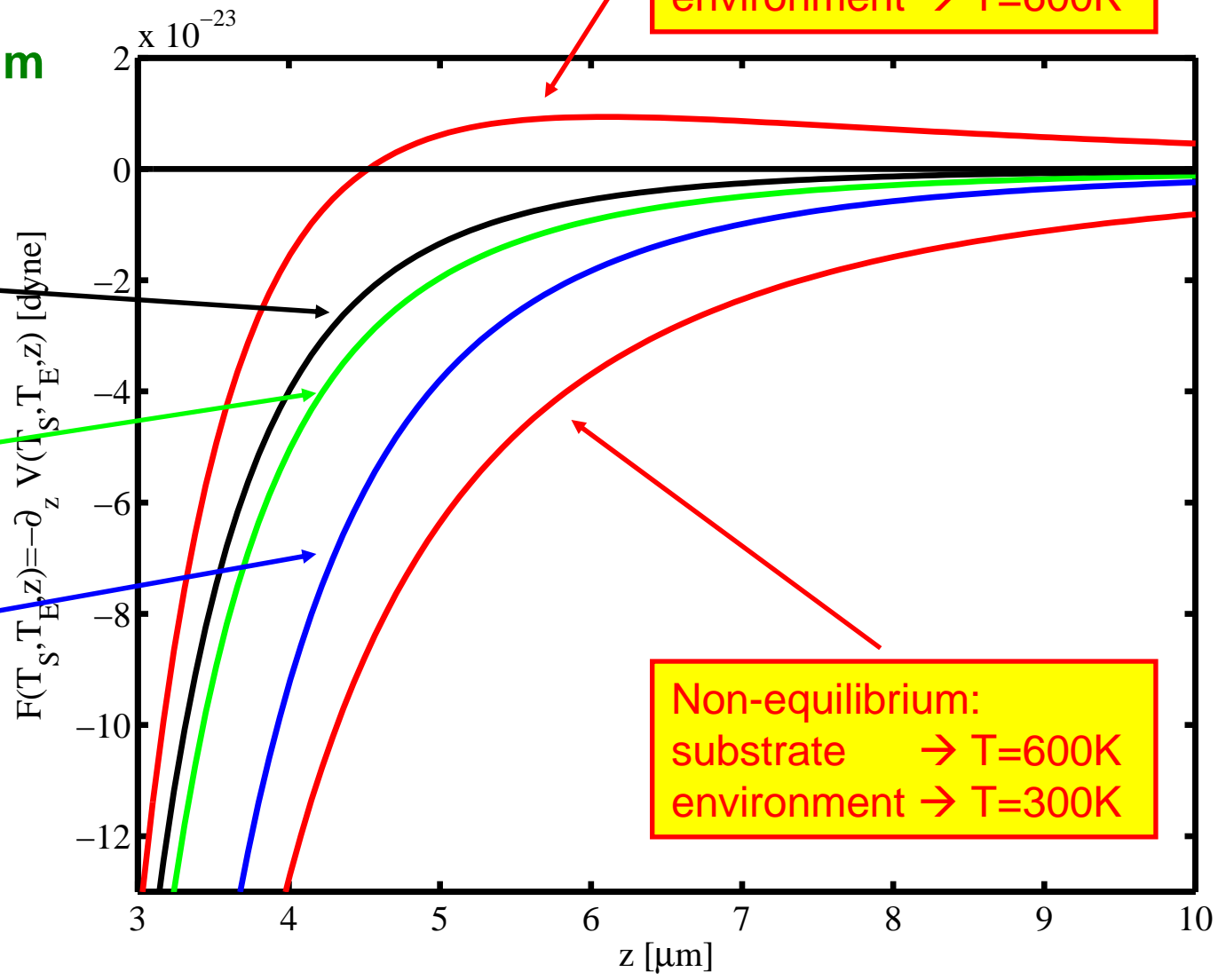
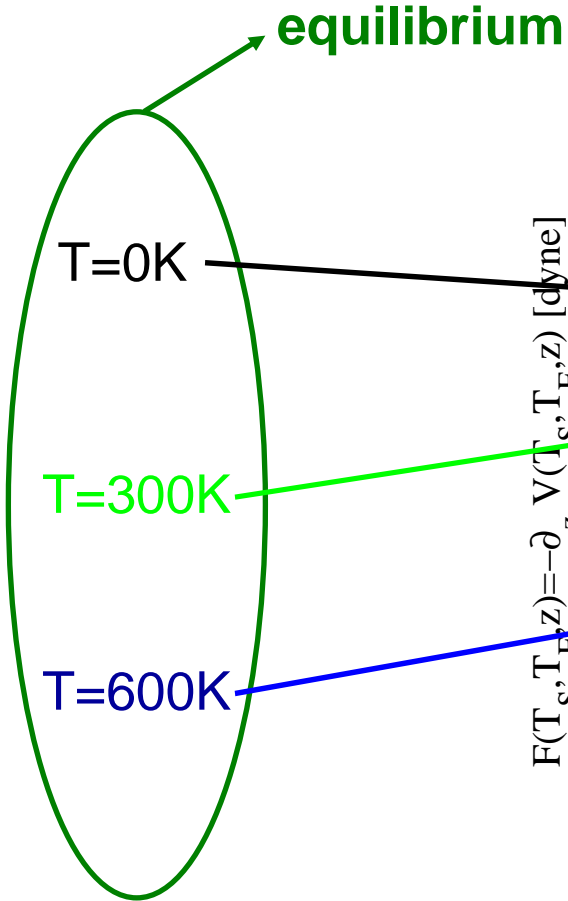
2. At  $\lambda_T / \sqrt{\epsilon_2 - 1} \ll l$ :

$$P^{neq} \propto \frac{k_B T}{l^3} \sqrt{\epsilon_2 - 1}$$

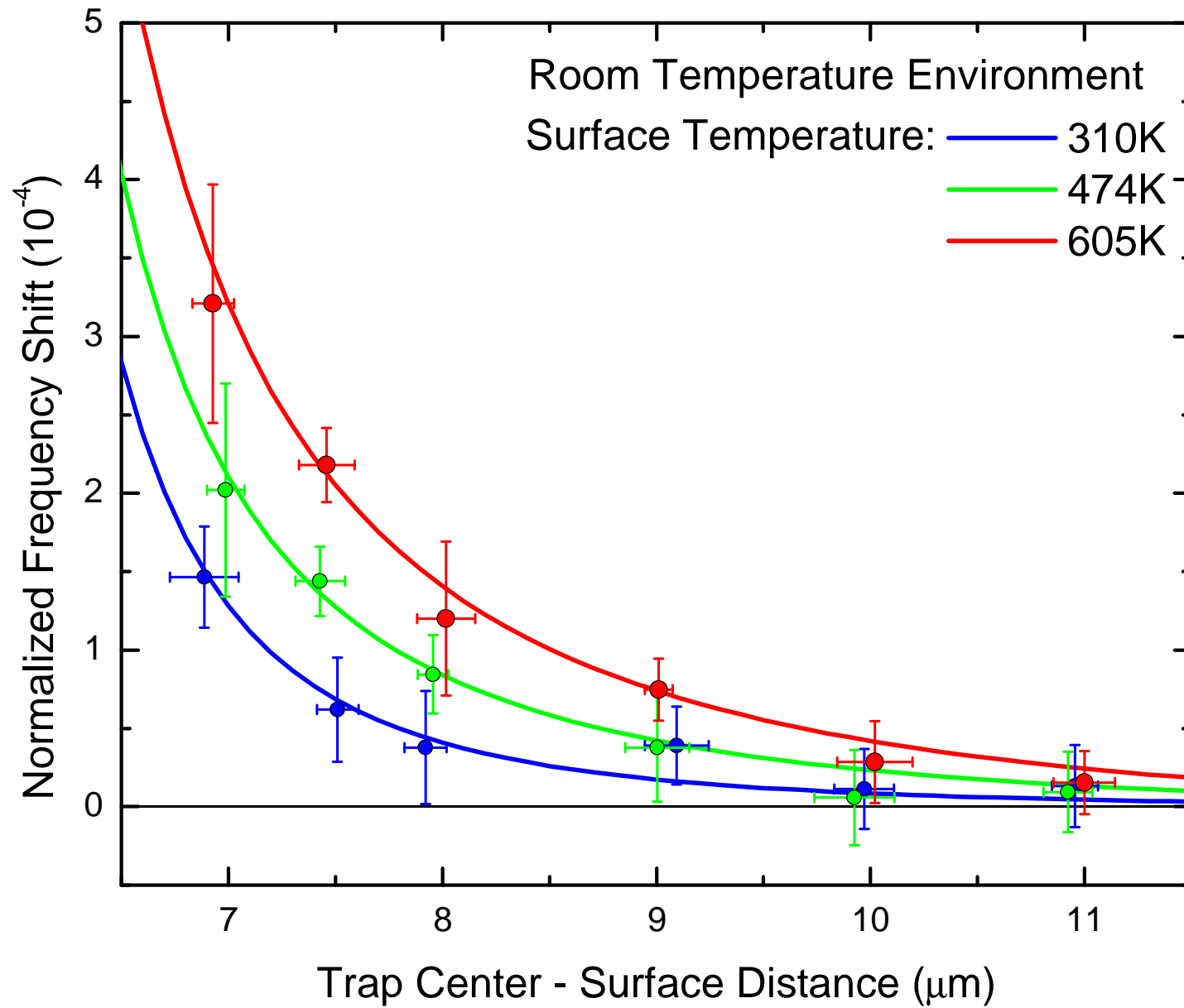
**Non-additivity!**

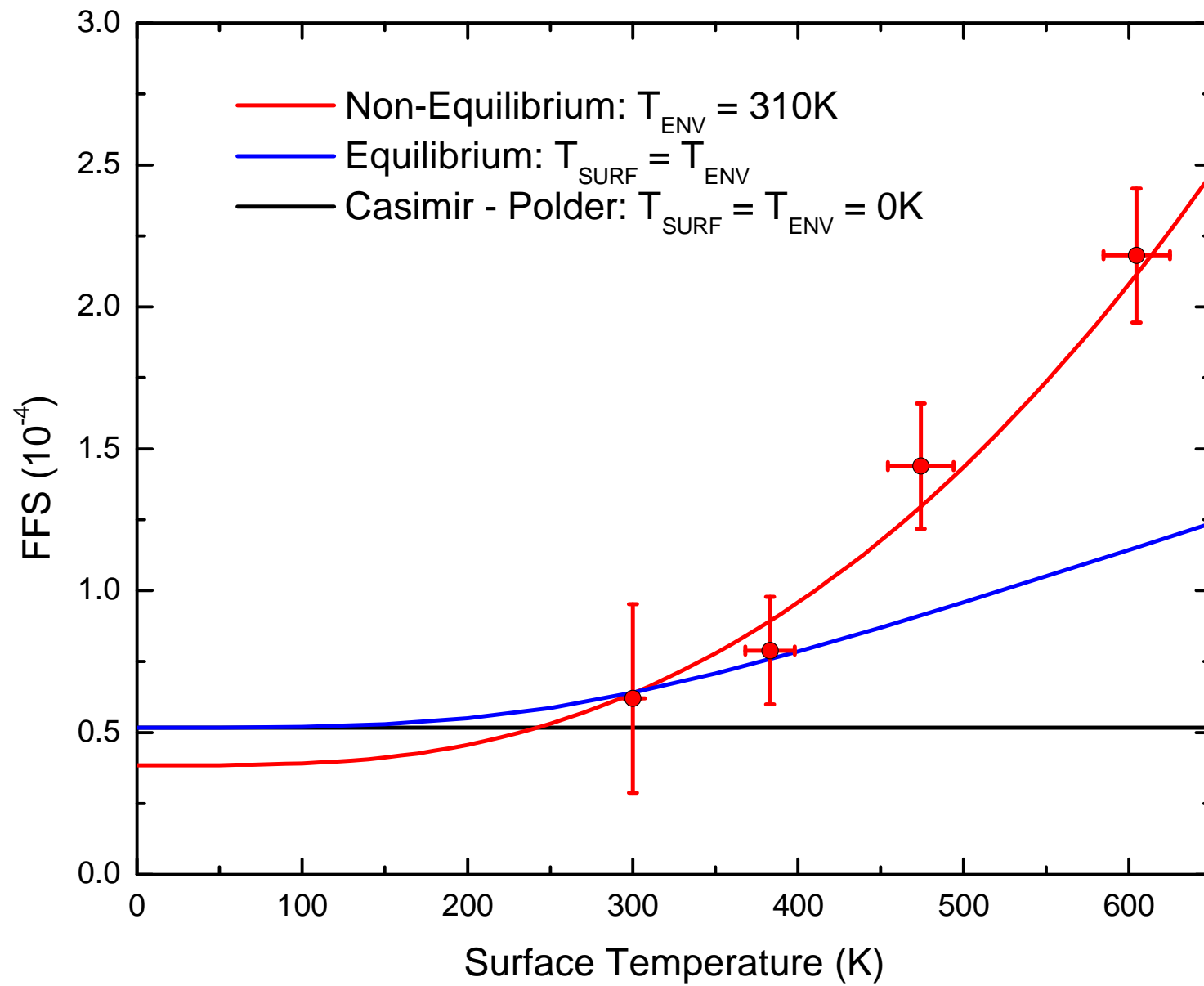
# Thermal effects on the surface-atom force

- Sapphire substrate
- Rubidium atoms



# Recent Experimental results from JILA





# Paradox of Lifshitz theory

$$l \gg \hbar c / T$$

Only  $s = 0$  term is important

$$V(l) = -\frac{T}{4l^3} \frac{\epsilon_0 - 1}{\epsilon_0 + 1}$$

$$\epsilon(i\zeta) = \frac{4\pi\sigma}{\zeta} + \bar{\epsilon}, V(l) = -\frac{T}{4l^3}$$

$$\sigma \rightarrow 0 ???$$



# Debye screening of the field

$$z < 0, [\Delta - \kappa^2] \varphi = 0$$

$$\kappa^2 = R_D^{-2} = \frac{4\pi e^2 n}{\epsilon T}$$

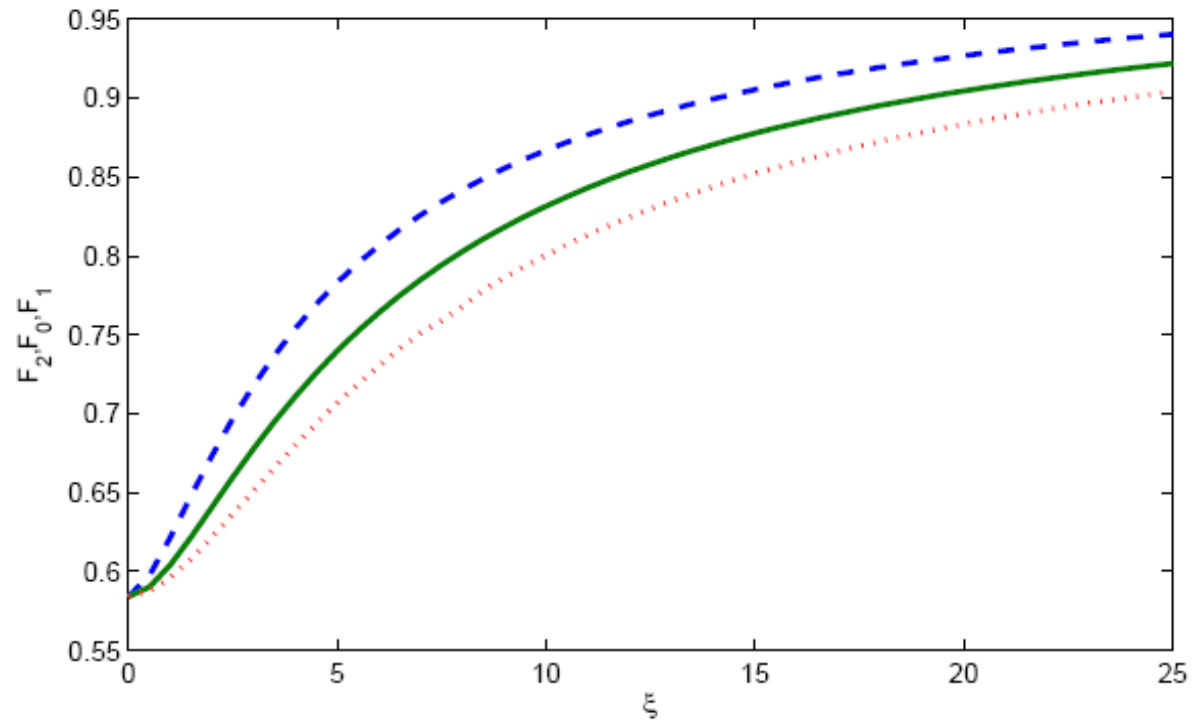
$$q = \sqrt{k^2 + \kappa^2}$$

$$V(l) = -T\alpha_0 \int_0^\infty \frac{\epsilon q - k}{\epsilon q + k} e^{-2kl} k^2 dk$$

$$\equiv -\frac{T\alpha_0}{4l^3} F_0(\xi = l/R_D)$$

L. Pitaevskii (2008)

# Effect of the field penetration



# Fused Silica: $\text{SiO}_2$

$$\bar{\varepsilon} = 3.81$$

Conductivity is due to  $\text{Na}^+$

$$c_{\text{Na}} = (50 - 100) \text{ppb},$$

$$n_{\text{Na}} = (2.88 - 5.76) \times 10^{15} \text{ cm}^{-3}$$

# Fused Silica: $T=605$ K

$$n_{Na} = (2.88 - 5.76) \times 10^{15} \text{ cm}^{-3}$$

$$R_D \leq 6.2 \times 10^{-2} \mu$$

$$\rho = 8.3 \times 10^{10} \text{ ohm.cm} = 9.3 \times 10^{-2} \text{ s}$$

$$\tau = \frac{\bar{\varepsilon} \rho}{4\pi} = 2.8 \times 10^{-2} \text{ s}$$

$$D = 8.5 \times 10^{-10} \text{ cm}^2 / \text{s} = bT$$

$$n_{Na}^D = \frac{T}{\rho D e^2} = 4.62 \times 10^{15} \text{ cm}^{-3}$$

# Fused Silica: $T=292$ K

$$n_{Na} = (2.88 - 5.76) \times 10^{15} \text{ cm}^{-3}$$

$$R_D \leq 4.3 \times 10^{-2} \mu$$

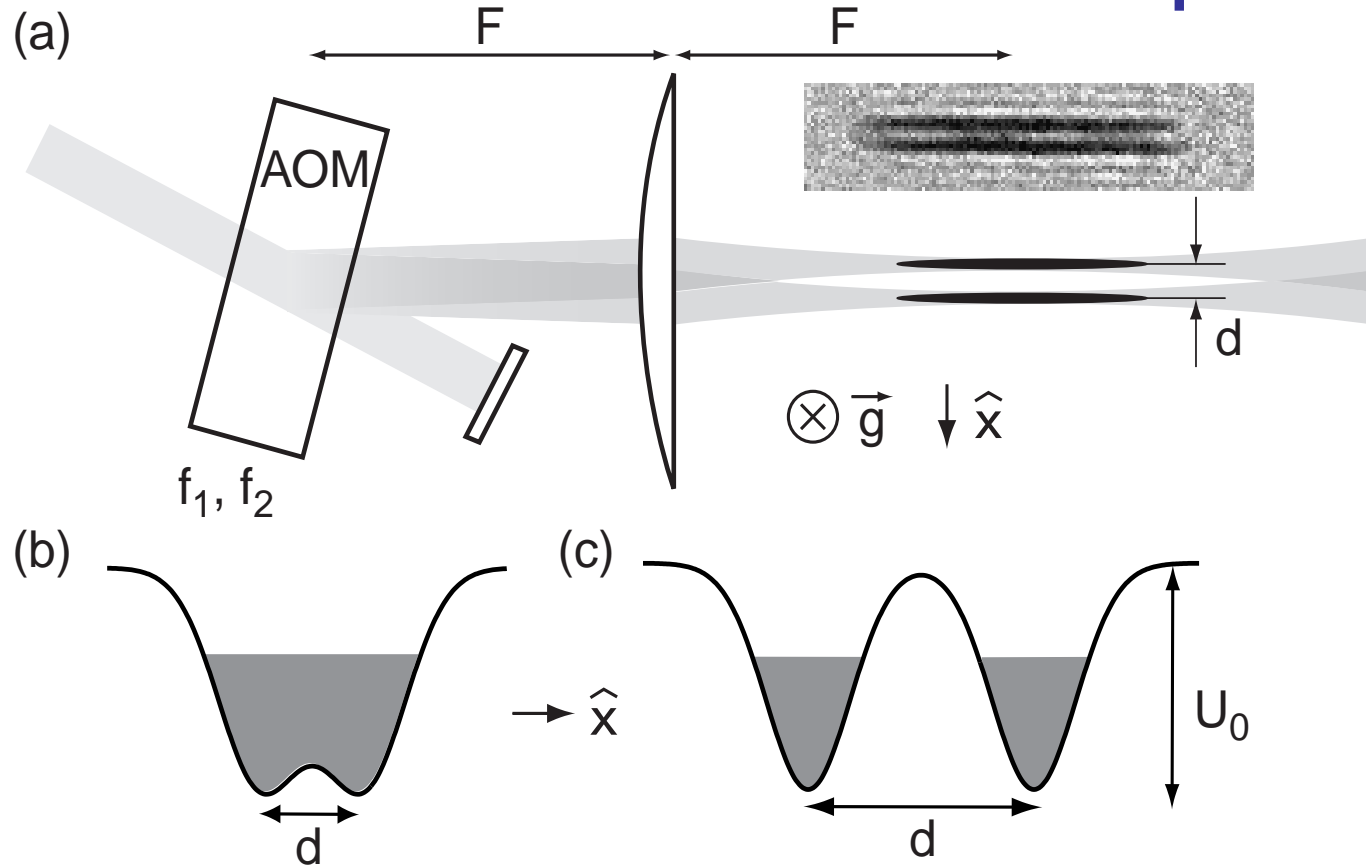
$$\rho = 10^{19} \text{ ohm.cm} = 1.1 \times 10^7 \text{ s} \sim 900h$$

$$\tau = \frac{\bar{\epsilon}\rho}{4\pi} = 3.3 \times 10^6 \text{ s}$$

$$D = 2.2 \times 10^{-20} \text{ cm}^2 / \text{s} = bT$$

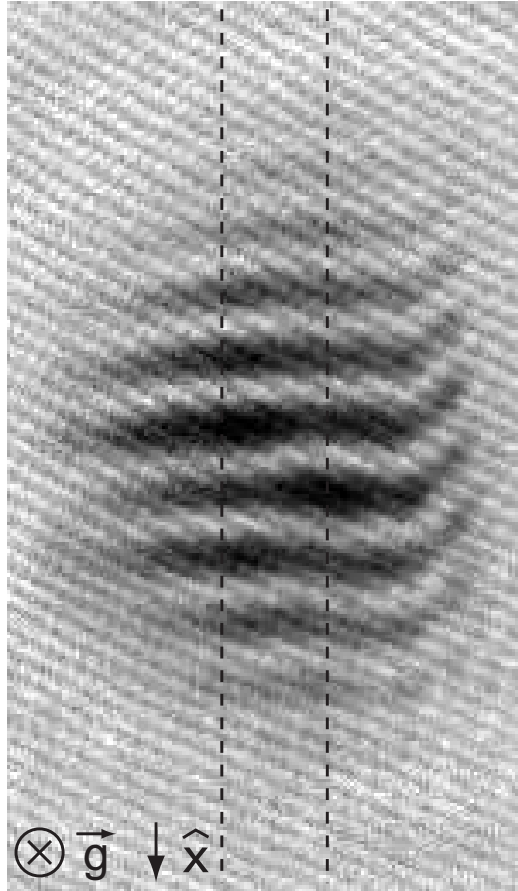
$$n_{Na}^D = \frac{T}{\rho D e^2} = 7 \times 10^{17} \text{ cm}^{-3} ???$$

# MIT double-well setup

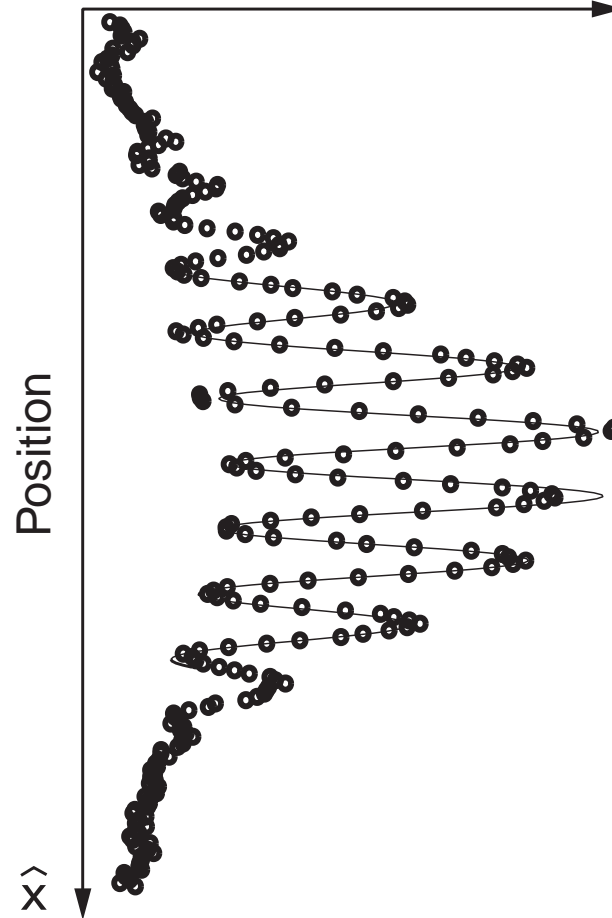


(a) Setup for double-well potential. (b), (c):  $d=6, 13$  cm  
Y. Shin, M. Saba, T. Pasquini, W. Ketterle, D. Pritchard, and A. Leanhard, PRL **92**, 050405 (2004).

(a)



(b) Integrated Optical Density



Interference of condensates released from the double-well trap [1].

# Measurement of the phase difference.

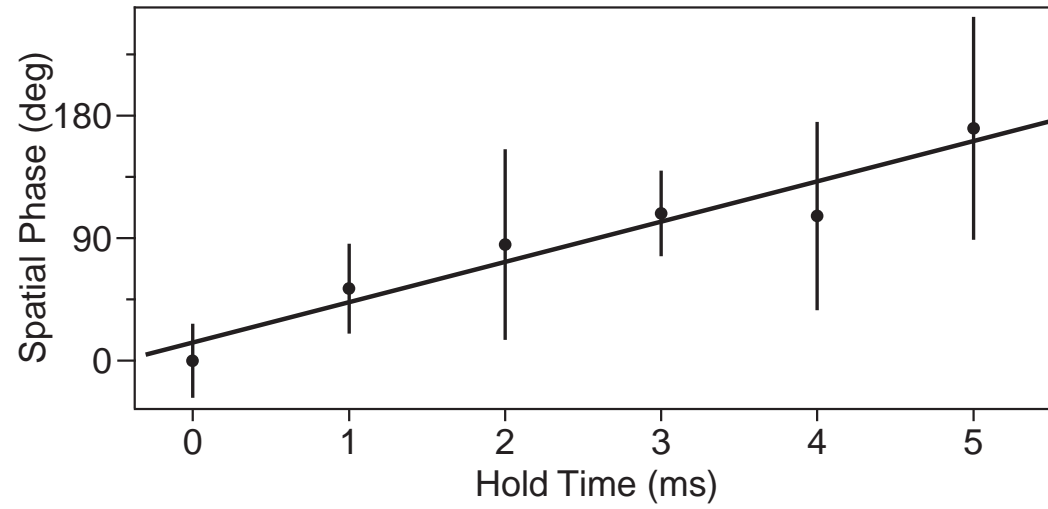
Interference of expanding condensates.

Density profile after expansion :

$$n(x, t) = \left[ n_a + n_b + 2\sqrt{n_a n_b} \cos\left(\frac{md}{\hbar t} x + \Phi\right) \right]$$

$$\Phi = \Delta t \langle U \rangle, U = -\int_z^{\infty} F dz$$





Time dependence of the relative phase in presence of chemical potentials difference [1].

# Measurement of the phase difference. II

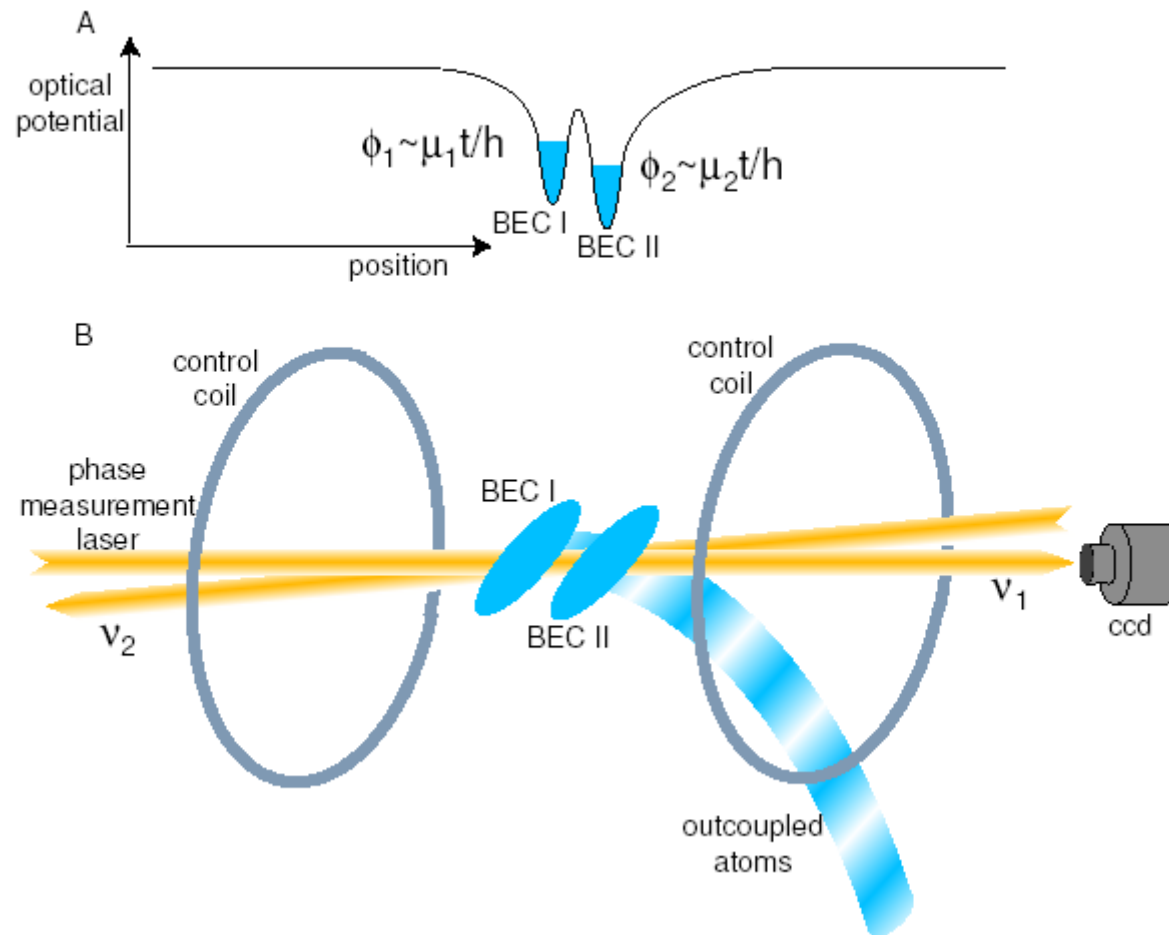
"Interference in momentum space"

Momentum distribution of two identical condensates in a double - well trap :

$$n(p_x) = 2 \left[ 1 + \cos \left( \frac{p_z d}{\hbar} + \Phi \right) \right] n_a(p_x)$$

Measurement can be almost non - destructive!

L. Pitaevskii and S. Stringari, 1999.



Setup for continuous phase measurement.  
 M. Saba, T. Pasquini, C. Sanner, Y. Shin, W.  
 Ketterle, and D. Pritchard, Science (2005).